Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.719 inches and 0.764 inches

Overall Diameter:

Between 0.622 inches and 0.628 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case and mounting hardware

Overall Width Across Flats:

0.750 inches

Thread Size:

0.625 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

8.5 breakdown voltage, dc

Current Rating Per Characteristic:

10.00 milliamperes repetitive peak forward current

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug

Specification Data:

81349-mil-19500/335 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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